## NSN 5961-01-375-0805

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#### **Inclosure Material:**

Plastic

**Overall Length:** 

2.9 millimeters

#### Overall Height:

1.3 millimeters

#### **Overall Width:**

1.5 millimeters

#### **End Application:**

6625-01-286-3566

#### Internal Configuration:

#### Junction contact

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

#### Sot-23

**Mounting Method:** 

### Terminal

**Features Provided:** 

Burn in

#### **Cubic Measure:**

5.656 cubic meters

#### Semiconductor Material:

Silicon

#### Voltage Rating In Volts Per Characteristic:

20.0 collector to base voltage/static/emitter open and 10.0 collector to emitter voltage/static/base open and 1.5 emitter to base voltage, static, collector open

#### **Current Rating Per Characteristic:**

65.00 milliamperes source cutoff current

#### **Power Rating Per Characteristic:**

200.0 milliwatts small-signal input power, common-collector preset

#### **Transfer Ratio:**

50.0 static forward current transfer ratio, common-emitter and 250.0 static forward current transfer ratio, common-emitter

#### Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

#### **Special Features:**

Junction pattern arrangement: npn

#### **Terminal Type And Quantity:**

3 uninsulated wire lead

#### Shelf Life:

N/a

#### Unit Of Measure:

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#### Demilitarization:

No

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